Single-Shot Measurement of Triplet-Singlet Relaxation in a Si/SiGe Double Quantum Dot

J. R. Prance,[1] Zhan Shi,[1] C. B. Simmons,[1] D. E. Savage,[1] M. G. Lagally,[1] L. R. Schreiber,[2] L. M. K. Vandersypen,[2] Mark Friesen,[1] Robert Joynt,[1] S. N. Coppersmith,[1] and M. A. Eriksson[1]

[1]*University of Wisconsin-Madison, Madison, Wisconsin 53706, USA*

[2]*Kavli Institute of Nanoscience, TU Delft, Lorentzweg 1, 2628 CJ Delft, The Netherlands*

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We investigate the lifetime of two-electron spin states in a few-electron Si/SiGe double dot. At the transition between the (1,1) and (0,2) charge occupations, Pauli spin blockade provides a readout mechanism for the spin state. We use the statistics of repeated single-shot measurements to extract the lifetimes of multiple states simultaneously. When the magnetic field is zero, we find that all three triplet states have equal lifetimes, as expected, and this time is ~10 ms. When the field is nonzero, the T_0 lifetime is unchanged, whereas the T_- lifetime increases monotonically with the field, reaching 3 sec at 1 T.

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The lifetimes of single electron spins in silicon have recently been measured to be as long as seconds in Si nanodevices, including gated quantum dots and donors [1–4], a promising step towards silicon spin qubits. Two-electron singlet-triplet states in a double dot can also be used as qubits [5–7], with the advantages that gating operations can be fast and that readout depends on the singlet-triplet energy splitting, which can be much larger than the single-spin Zeeman energy at low magnetic fields. The lifetimes of singlet and triplet states have been measured in GaAs double dots and were found to depend on the magnetic field, falling to <30 μs at zero field [8,9]. In silicon, neither a single-shot readout of the singlet-triplet qubit states nor a measurement of their lifetimes has been achieved up until now.

Here we report measurements of the lifetimes of singlet and triplet states in a Si/SiGe double quantum dot at magnetic fields from 1 T to 0 T obtained using single-shot readout. Using pulsed gate voltages, we repeatedly alternate the charge detuning so that it first favors the (1,1) charge state (one electron in each dot) and then the (0,2) charge state (two electrons in one of the dots). Because of Pauli spin blockade, charge transitions to (0,2) will only occur when the spin state is a singlet. We perform hundreds of thousands of such cycles and measure the presence or absence of charge transitions using real-time charge sensing. By analyzing the statistics of such data, we characterize multiple relaxation processes simultaneously, in contrast to time-averaged measurements, which are only sensitive to the rate-limiting process. When the magnetic field is zero the triplet and singlet state lifetimes are between 5 and 25 ms, lifetimes that exceed those measured in GaAs by over 2 orders of magnitude. As the magnetic field increases, the lifetime of the T_0 remains essentially constant, whereas the lifetime of the T_- increases dramatically, reaching 3 sec at $B_\parallel = 1$ T. These long times are expected because of the small hyperfine coupling and spin-orbit interaction in Si quantum dots.

The device is fabricated on a phosphorus-doped $Si/Si_{0.7}Ge_{0.3}$ heterostructure with a strained Si quantum well approximately 75 nm below the surface. Palladium surface gates labeled 1–9 in Fig. 1(a) are used to form the

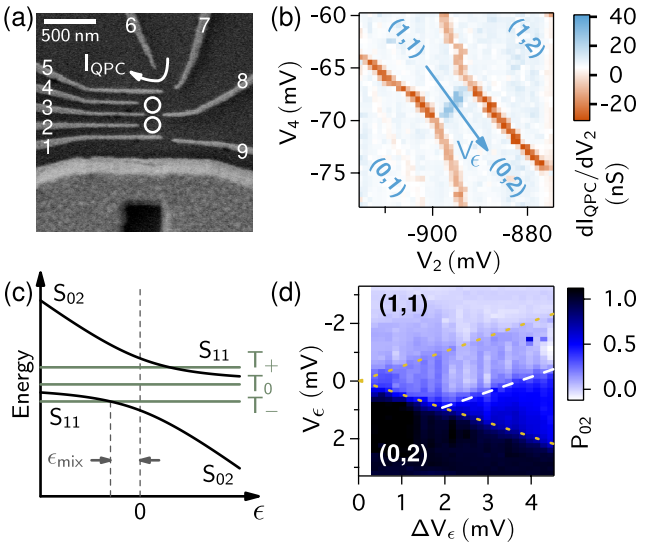

FIG. 1 (color online). (a) Scanning electron microscopy (SEM) image of a device identical to the one used. Quantum dots are formed at the approximate locations of the two circles. Charge sensing is performed by monitoring the current I_{QPC} through a nearby point contact. (b) Charge stability diagram of the double dot showing the detuning voltage V_ϵ. (c) Energies of two-electron states as a function of detuning energy ϵ. T_+, T_0, and T_- are the (1,1) triplets; the (0,2) triplets are higher in energy. The (1,1) and (0,2) singlets S_{11} and S_{02} are coupled by spin-preserving, interdot tunneling. A magnetic field separates the triplet energies by $E_z = g\mu_B B$. (d) Time-averaged occupation of the (0,2) charge state P_{02} at $B_\parallel = 0$ with 5 kHz square pulses of peak-to-peak amplitude ΔV_ϵ applied along V_ϵ. The pulses drive (1,1)-(0,2) transitions within the dotted triangle. The suppression of P_{02} above the dashed line shows where (1,1) to (0,2) tunneling is suppressed by spin blockade.

double-dot confinement potential [10]. A thick rf antenna (Ti/Au, 5 nm/305 nm) is also present near the dot gates, but is unused in this experiment. All gates are connected to room-temperature voltage sources via cold RC filters, which are at the measurement base temperature of ≈ 15 mK. Gates 2 and 4 are also ac coupled to coaxial lines, allowing them to be pulsed at frequencies between 100 Hz and 1 GHz. There is an attenuation of ≈ 50 dB between each gate and the pulse source. (See [11] for details of the pulse amplitude calibration.) Current through the device is measured with a room-temperature current preamplifier with a bandwidth ≈ 1 kHz.

Figure 1(b) shows a charge stability diagram in which the absolute occupation of the dots was found by emptying both dots and then counting electrons back in. Figure 1(c) shows the predicted energies of the two-electron states near the (1,1)-(0,2) transition as a function of detuning energy ϵ, where the transition is at $\epsilon = 0$ [12]. The detuning energy is controlled by varying the voltages on gates 2 and 4 along V_ϵ, shown in Fig. 1(b). The interdot tunnel coupling t_c was measured by determining where the S_{11} and T_- states cross at finite $B_\parallel$. This is shown as ϵ_{mix} in Fig. 1(c), and depends on both $B_\parallel$ and the curvature of the avoided singlet crossing. Using this approach [6], we find $t_c = 2.8 \pm 0.3$ μeV (677 $\pm$ 73 MHz.)

To measure the spin of a (1,1) state we pulse the system into a spin blockaded configuration [13–15], where the ground state of the system is S_{02} and the (0,2) triplet states are higher in energy than all of the (1,1) triplets: T_-, T_0, and T_+. We characterize the parameters needed to reach this configuration by detecting spin blockade in the time-averaged measurement shown in Fig. 1(d). Square pulses at 5 kHz are applied along V_ϵ. The color scale in Fig. 1(d) shows the time-averaged probability P_{02} of finding the system in (0,2) as a function of pulse amplitude and offset along V_ϵ. When the pulse crosses the (1,1)-(0,2) transition, tunneling between charge states results in $0 < P_{02} < 1$. The region where this occurs is bounded by the dotted triangle in Fig. 1(d). Spin blockade occurs in the part of the pulse triangle that is above the dashed white line in Fig. 1(d). Here we see $0 < P_{02} < 0.5$, because the system is residing in (1,1) the majority of the time.

Spin blockade does not occur below the white dashed line in Fig. 1(d), resulting in $P_{02} \approx 0.5$. In this region the pulse amplitude exceeds the (0,2) singlet-triplet splitting energy E_{ST}, and the pulse offset is such that the (0,2) triplet states have lower energy than the (1,1) triplets. From the size of the blockaded region, and the conversion from detuning voltage V_ϵ to detuning energy ϵ ($\Delta\epsilon = \Delta V_\epsilon \times 0.0676$ eV/V, see [11] for additional details), we find $E_{\mathrm{ST}} = 124 \pm 4$ μeV.

Figures 2(a) and 2(b) show single-shot initialization and readout of (1,1) singlet and triplet states using real-time measurement of the charge state while pulsing across the (1,1)-(0,2) transition. The system is initialized by starting from the ground state S_{02} at $0 < \epsilon < E_{\mathrm{ST}}$. The occupation

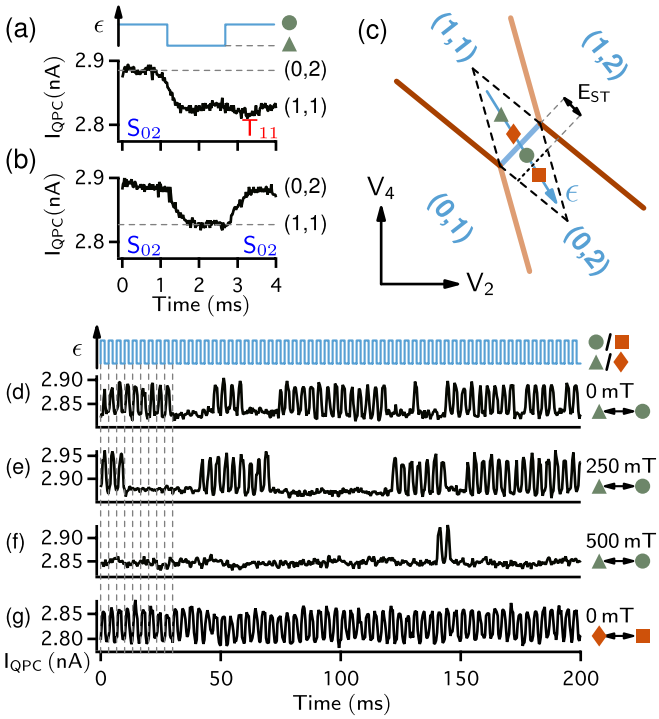

FIG. 2 (color online). Single-shot initialization and readout of singlet and triplet states. (a),(b) Real-time measurements of I_{QPC} as the system is initialized to S_{11} then read out 1.7 ms later. We identify the final state in (a) as one of the (1,1) triplets (T_{11}) because the (1,1) charge state survives for over 1 ms during the readout. In (b) a singlet is identified because the system tunnels quickly back to (0,2) during the readout. (c) Schematic stability diagram. The points marked are the four detuning values used in the measurements. At $B_\parallel > 0$, E_{ST} is decreased by $g\mu_B B_\parallel$. The pulse is offset to keep the circle inside the blockaded region without changing the separation of the circle and triangle points. Dashed triangles bound the region where (1,1)-(0,2) transitions occur primarily by interdot tunneling. (d)–(g) Pulses repeatedly switch the ground state between (1,1) and (0,2) at 300 Hz. In (d)–(f) the system is often blockaded in a (1,1) triplet. With increasing magnetic field from (d) to (f), the durations of blockade increase significantly. In (g), the pulse reaches into (0,2) far enough to exceed E_{ST}, and tunneling from (1,1) to (0,2) occurs freely for all spin states.

of S_{02} is verified by measuring the charge state: S_{02} is the only (0,2) state accessible at this detuning. We then pulse to $\epsilon < 0$ to transfer the prepared S_{02} to the (1,1) singlet S_{11}. To measure the (1,1) spin state at some later time, we pulse back to $0 < \epsilon < E_{\mathrm{ST}}$ where a singlet can tunnel quickly to (0,2) but the triplets cannot. The measurements are performed using detuning pulses with two levels that are at the positions of the filled triangle and circle in Fig. 2(c), which correspond to detuning energies of $\epsilon \approx -160$ μeV and 60 μeV, respectively, at $B_\parallel = 0$.

We measure the lifetimes of the (1,1) singlet and triplet states by detecting the spin state as we repeatedly pulse back and forth across the (1,1)-(0,2) transition at a frequency of 300 Hz. Figures 2(d)–2(f) show real-time measurements of the charge state as the pulses are applied. In

this regime spin blockade is active and the system switches randomly between free shuttling of a singlet state and blockade of a (1,1) triplet state. The typical length of time spent in a blockaded triplet increases dramatically as $B_{\|}$ increases. Figure 2(g) is a control, demonstrating that charge shuttles freely in both directions when the pulse is offset to reach outside the spin-blockade regime.

To determine the lifetimes of the states at $B_{\|} = 0$ we plot in Figs. 3(a) and 3(b) the number of times that blockaded periods of duration t_b and unblockaded periods of duration t_u are observed in 6.4 minutes of data (115 200 pulse periods). The histograms are very well fit by exponential decays, and fits to the two distributions give characteristic times of $\tau_b = 9.6 \pm 0.2$ ms for the blockaded configuration and of $\tau_u = 23 \pm 3$ ms for the unblockaded configuration. From these times we find that the lifetimes of the spin states are ~10 ms, using a rate-equation model that we describe below.

The $B_{\|} = 0$ lifetimes are 2 orders of magnitude longer than have been seen in comparable low-field measurements of GaAs quantum dots [8,9]. We suggest that this is due to the small hyperfine coupling in natural silicon, arising from the high abundance of zero-spin nuclei. At $B_{\|} = 0$, the (1,1) triplets are degenerate and separated from S_{11} by an energy $J(\epsilon) \approx t_c^2/\epsilon$. We expect singlet-triplet mixing to be driven by a small magnetic field difference between the two dots, resulting from the contact-hyperfine interaction with nuclear spins [16–18]. Predictions for the hyperfine coupling of (1,1) spin states are $h \sim 3$ neV in silicon [18], compared to measured values of $h \sim 50$ neV in GaAs [8,19]. The expected coupling is small enough that, in our measurements, it would be exceeded by the exchange splitting J. Given t_c and the pulse amplitude, hyperfine induced singlet-triplet mixing should be suppressed by a factor of $[1 + (J/h)^2] \sim 500$, compared to the maximum mixing rate when $J \ll h$.

The values τ_u and τ_b are determined by the rate of singlet-triplet mixing, but they do not directly correspond to mixing times in any static configuration of the system. This is because the pulses continuously switch between two configurations, one at $\epsilon < 0$ and one at $\epsilon > 0$. The singlet-triplet mixing times may be different in the two configurations, and at $\epsilon > 0$ there are also fast, one-way transitions from S_{11} to S_{02}. We relate the measured values of τ_b and τ_u to singlet-triplet mixing times in the two configurations of the system by using rate equations to model state occupations during a single pulse cycle. The inputs to the model are 2 times; one time τ_- is the mixing time when the ground state is S_{11} during the $\epsilon < 0$ half of the pulse, and the other time τ_+ is the mixing time when the ground state is S_{02} during the $\epsilon > 0$ half of the pulse. Tunneling between S_{11} and S_{02} is assumed to be instantaneous. Mixing during the pulse transitions is ignored because the period of the pulse is 10^5 times larger than the pulse rise time. We solve for τ_+ and τ_- by numerical optimization of the model to match the measured values of τ_u and τ_b (see [11] for additional details). We find $\tau_- = 24.5 \pm 3$ ms and $\tau_+ = 5.8 \pm 0.3$ ms. We attribute the difference between τ_+ and τ_- to a difference in t_c between the two halves of each pulse cycle.

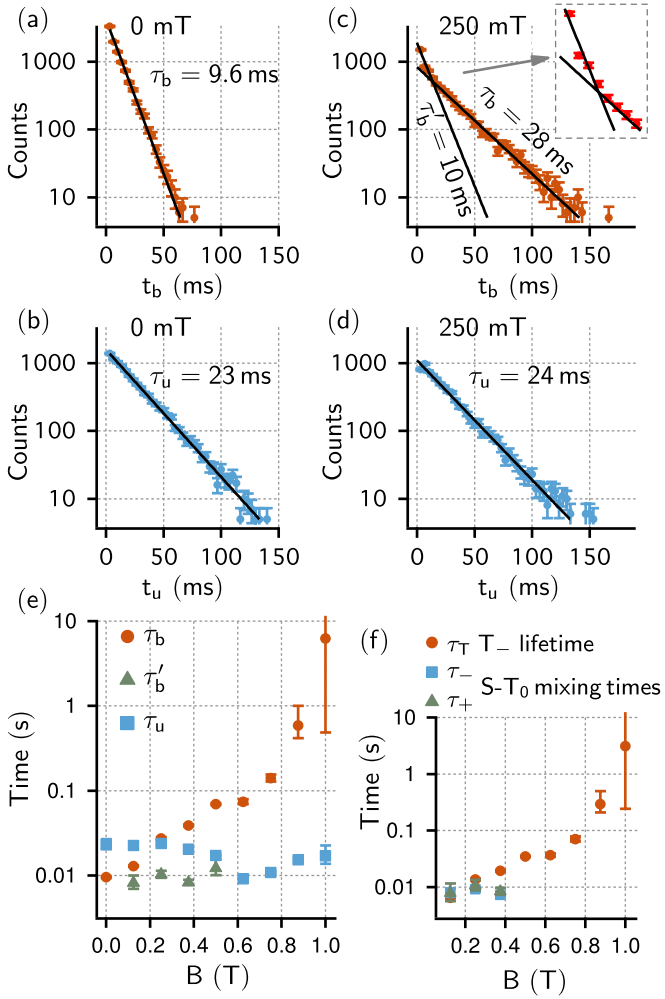

FIG. 3 (color online). (a) Histogram of the number of times that the system is blockaded for a time t_b in many measurements such as Fig. 2(d). The binning resolution is the pulse period. The solid line is an exponential fit yielding a characteristic time $\tau_b = 9.6$ ms for the blockaded configuration. (b) Histogram of unblockaded times t_u for the same data as (a). An exponential fit yields a characteristic time $\tau_u = 23$ ms for the unblockaded configuration. (c),(d) Histograms of t_u and t_b at $B_{\|} = 250$ mT. There are two decays describing the blockade: at small t_b the decay is similar to that at zero field ($\tau_b' = 10$ ms). At long t_b a slower decay dominates ($\tau_b = 28$ ms). We interpret the shorter time as arising from T_0 occupation, and the longer time as arising from T_- occupation. (e) Fitted characteristic times as a function of magnetic field. The characteristic time of blockade due to T_- states τ_b increases with field, while the contributions from T_0 and S_{11} states τ_b' and τ_u are field independent. (f) T_- lifetime τ_T, and S_{11}-T_0 mixing rate at positive (negative) detuning τ_+ (τ_-).

As $B_{\|}$ increases from 0 T, we observe a qualitative change in the spin dynamics: the statistics of the blockaded durations show two separate characteristic times. As shown

in Figs. 3(c) and 3(e), there are short blockaded periods with a characteristic time τ_b' that is field independent, and there are longer blockaded periods whose characteristic time τ_b increases with field. The 2 times arise because the system can be blockaded if it is in either a T_0 or a T_- state, and the T_- has a field dependent energy, whereas the T_0 does not. The T_+ state does not play a role at $B_\parallel > 0$ because its higher energy means that it is rarely populated. Combined with statistics of unblockaded durations, as in Fig. 3(d), each measurement at $B_\parallel > 0$ can contain simultaneously information about the lifetimes of three states: S_{11}, T_-, and T_0.

Figure 3(f) shows the T_- lifetime τ_T and S_{11}-T_0 mixing times τ_+ and τ_- calculated from the data in Fig. 3(e). We find τ_+ and τ_- from τ_u and τ_b' using a rate-equation model similar to the zero field case, but with no transitions to T_+ and T_- included. This is because mixing from the S_{11} or T_0 to the T_+ and T_- will be suppressed due to their separation in energy. At $B_\parallel \geq 0.5$ T, the system spends so much time in the T_- state that it is impractical to collect enough statistics to accurately determine τ_b'. Within the range of $B_\parallel$ where τ_b' can be measured, the S_{11}-T_0 mixing rates are largely independent of field and similar to the rates seen at $B_\parallel = 0$.

The time τ_T is the lifetime of the T_- during the $\epsilon > 0$ half of the pulse and is well approximated as $\tau_T = \tau_b/2$ at high magnetic fields. During the $\epsilon < 0$ half of the pulse, T_- is the ground state and it will remain populated with high probability when $g\mu B_\parallel > k_B T$. In the $\epsilon > 0$ half of the pulse the T_- is the first excited state and can decay to the S_{02} ground state at a rate of τ_T^{-1}. Such transitions could be induced by phonons and a spin nonconserving process such as hyperfine coupling [8,16,17] or spin-orbit coupling [20–23]. We find that the T_- lifetime τ_T increases strongly with field, rising to 3 sec by $B_\parallel = 1$ T. This is consistent with single-spin lifetimes measured at similar magnetic fields [1–4].

In summary, we have shown that we can initialize the singlet-triplet qubit state into a singlet and subsequently measure, in single-shot mode, transitions to the (1,1) triplet states. Using this initialization and real-time measurement, we have measured the lifetime of singlet and triplet states versus magnetic field. When the magnetic field is zero, the lifetime for the singlet and all three triplets is $\sim$10 ms. When the magnetic field is nonzero, the T_0 and S_{11} lifetimes are almost unchanged, whereas the T_- lifetime grows significantly, reaching 3 sec at 1 T.

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